

ES1AB THRU ES1JB

VOLTAGE RANGE 50 to 600 Volts

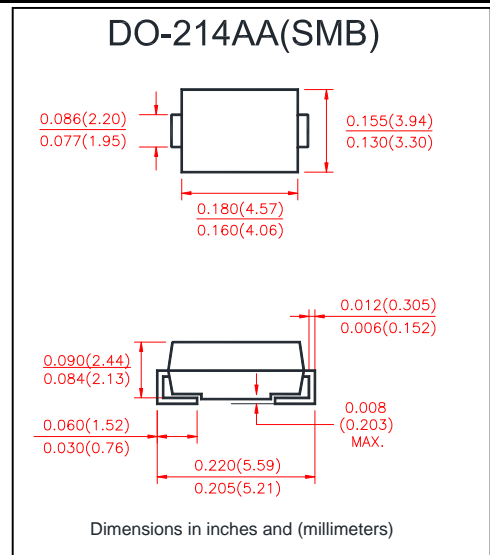
CURRENT 1.0 Ampere

FEATURES

- Plastic package has underwrites laboratory flammability Classification 94V-0
- Glass passivated chip junction
- Built-in strain relief
- Super Fast switching speed for high efficiency
- High temperature soldering guaranteed 250°C/10 seconds

MECHANICAL DATA

- Case: JEDED DO-214AA Transfer molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified.
- Single phase, half wave, 60Hz, resistive or inductive load.
- For capacitive load derate current by 20%.

	SYMBOLS	ES 1AB	ES 1BB	ES 1CB	ES 1DB	ES 1EB	ES 1GB	ES 1JB	UNIT	
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	Volts	
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	Volts	
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	Volts	
Maximum Average Forward Rectified Current At $T_A=55^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	1.0							Amps	
Peak Forward Surge Current 8.3ms single half sine wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							Amps	
Maximum Instantaneous Forward Voltage at 1.0A	V_F	0.95			1.25		1.7		Volts	
Maximum DC Reverse Current at rated DC blocking voltage at	$T_A = 25^\circ\text{C}$	5.0							μA	
	$T_A = 125^\circ\text{C}$	100								
Maximum Reverse Recovery Time Test conditions $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$	t_{rr}	35							nS	
Typical Junction Capacitance (Measured at 1.0MHz and applied reverse voltage of 4.0V)	C_J	10				8				pF
Typical Thermal Resistance (NOTE 1)	$R_{\theta JA}$	88							$^\circ\text{C}/\text{W}$	
	$R_{\theta JL}$	28								
Operating Junction Temperature	T_J	(-55 to +150)							$^\circ\text{C}$	
Storage Temperature Range	T_{STG}	(-55 to +150)							$^\circ\text{C}$	

Notes:

1. Thermal resistance from Junction to ambient and from junction to lead mounted on PCB. with 0.2×0.2" (5.0 × 5.0mm) copper pad areas.



WEET Technology Company Limited

Ultra-Fast Recovery Rectifiers

ES1AB THRU ES1JB

VOLTAGE RANGE 50 to 600Volts
CURRENT 1.0 Ampere

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

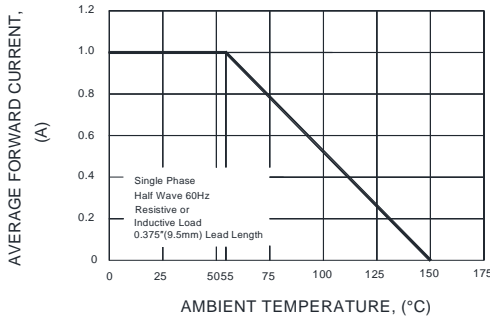


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

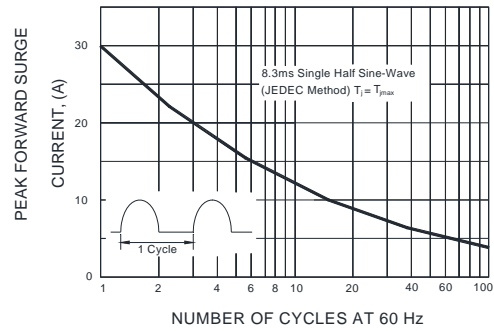


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

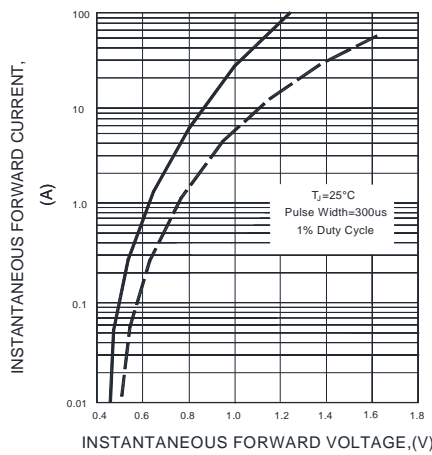


FIG.4-TYPICAL REVERSE CHARACTERISTICS

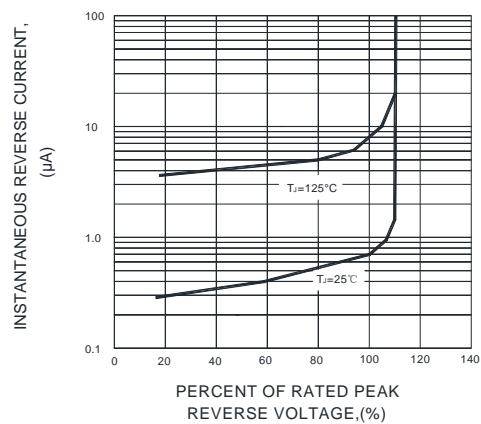


FIG.5-TYPICAL JUNCTION CAPACITANCE

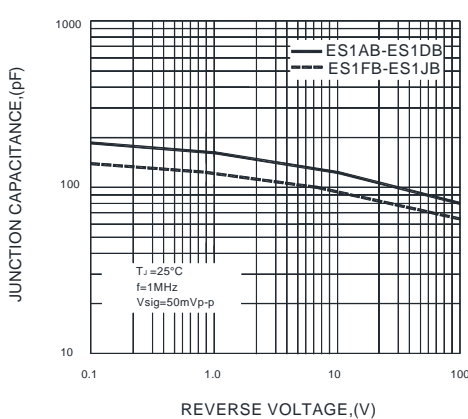
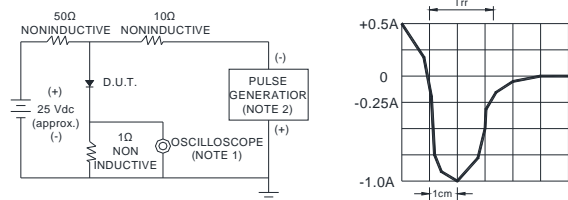
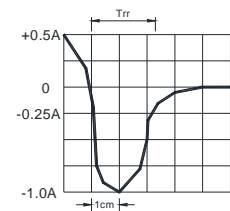


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES : 1. Rise Time=7ns max. Input Impedance= 1 magohm. 22pF
2. Rise time=10ns max. Source Impedance= 50 ohms



SET TIME BASE FOR 50/100ns/cm

Note: Specifications are subject to change without notice. For more detail and update, please visit our website.